



DMN10H220LQ

### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) max	I <sub>D max</sub> T <sub>A</sub> = +25°C
100\/	220mΩ @ $V_{GS}$ = 10V	1.6A
100V	$250m\Omega @ V_{GS} = 4.5V$	1.3A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

Load Switch

### **100V N-CHANNEL ENHANCEMENT MODE MOSFET**

# **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

# **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.009 grams (Approximate)

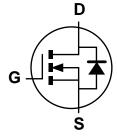
SOT23

Top View



Pin Configuration

D



Equivalent Circuit

### Ordering Information (Note 5)

Part Number	Case	Packaging
DMN10H220LQ-7	SOT23	3,000/Tape & Reel
DMN10H220LQ-13	SOT23	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

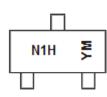
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3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



N1H = Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M = Month (ex: 9 = September)

### Date Code Key

Year	201	6	2017		2018	20	19	2020		2021	1	2022
Code	D		E		F	(	G	Н				J
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V <sub>DSS</sub>	100	V	
Gate-Source Voltage		V <sub>GSS</sub>	±16	V	
	(Note 7)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	1.6 1.3	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$	(Note 6)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	1.4 1.1	A
Maximum Continuous Body Diode Forward Curren	nt (Note 7)	Is	0.6	А	
Pulsed Drain Current (10µs pulse, duty cycle = 1%	<b>6</b> )	IDM	8	А	

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Tatal Dawar Dissinction (Nata Z)	T <sub>A</sub> = +25°C	D	1.3	W	
Total Power Dissipation (Note 7)	T <sub>A</sub> = +70°C	PD	0.8		
Thermal Registered, Junction to Ambient	(Note 6)	Р	94	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	177	C/VV	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

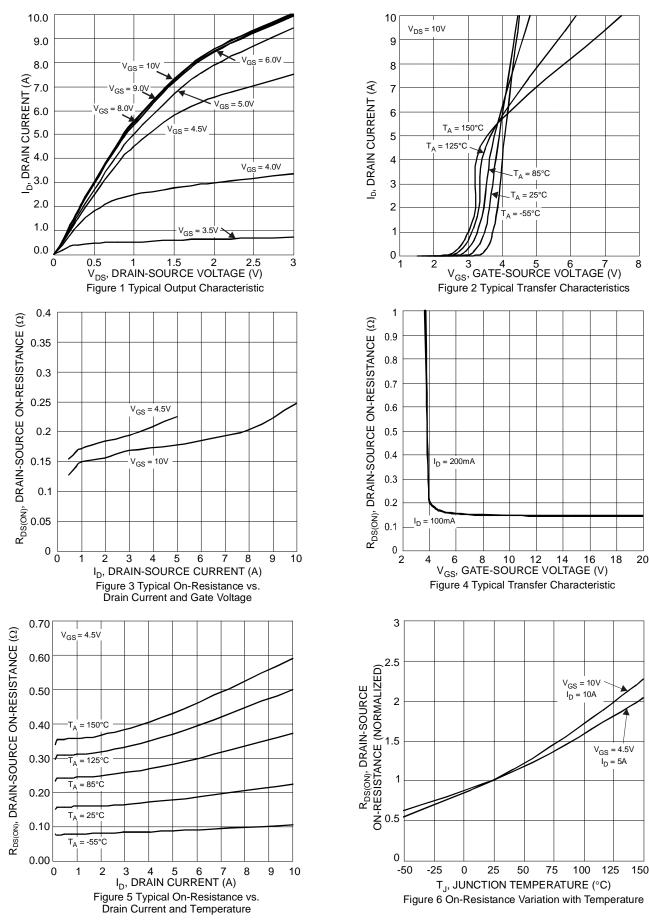
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS} = 100V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	2.5	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance			-	220	mΩ	$V_{GS} = 10V, I_D = 1.6A$
	R <sub>DS(ON)</sub>	—	_	250	11152	$V_{GS} = 4.5V, I_D = 1.3A$
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	401	—		
Output Capacitance	C <sub>oss</sub>	—	22	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	17	_		
Gate Resistance	Rg	_	2.1	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	4.1	_		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	8.3	—	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	1.5	_	nc	$V_{DS} = 50V, I_D = 1.6A$
Gate-Drain Charge	Q <sub>qd</sub>	_	2	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.8	_		
Turn-On Rise Time	t <sub>R</sub>	_	8.2	_		$V_{DS} = 50V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	7.9	_	ns	$R_{G} = 6.8\Omega, I_{D} = 1A$
Turn-Off Fall Time	tF	_	3.6	_	1	
Reverse Recovery Time	t <sub>RR</sub>	_	17	—	ns	
Reverse Recovery Charge	Q <sub>RR</sub>	_	9.8	_	nC	$I_F = 1.1A$ , di/dt =100A/µs

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.

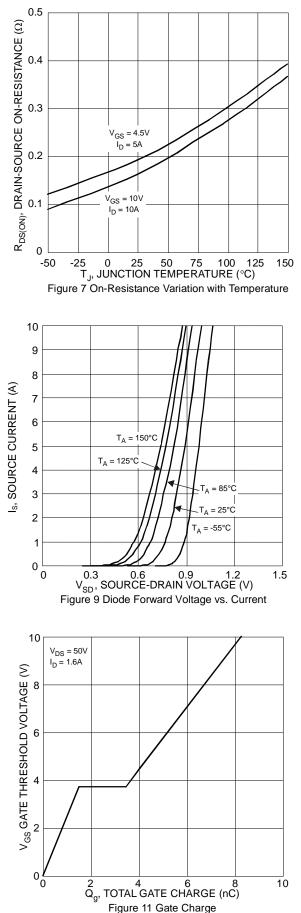


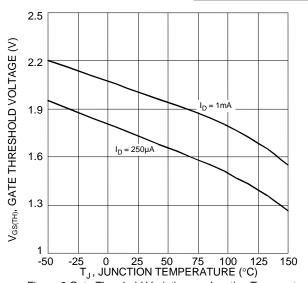


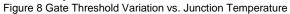
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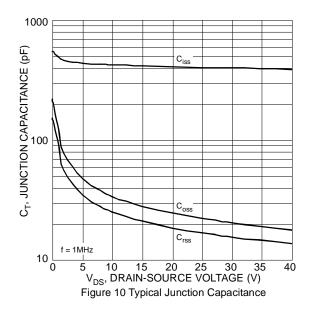




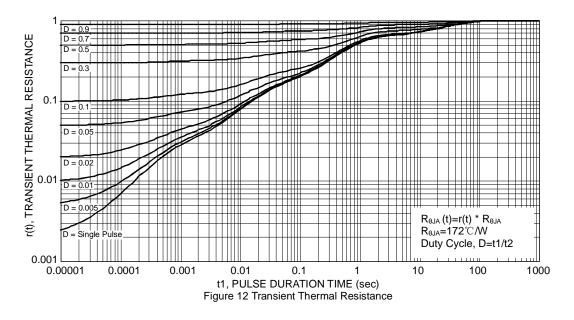










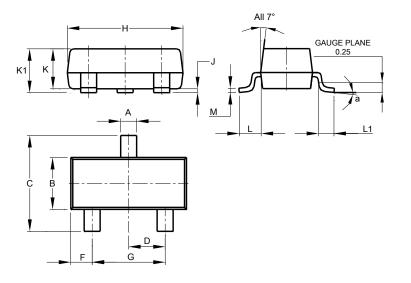




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

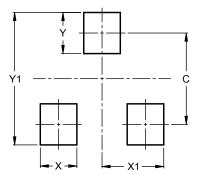


	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
K	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	0°	8°							
All	All Dimensions in mm								

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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